

PATENT  
4392-0149P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant:	Shih-Fan KUAN et al.	Conf.:
Appl. No.:	NEW	Group:
Filed:	December 23, 2003	Examiner:
For:	METHOD FOR FORMING DRAM CELL BIT-LINE CONTACT	

**PRELIMINARY AMENDMENT**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

December 23, 2003

Sir:

The following preliminary amendments and remarks are respectfully submitted in connection with the above-identified application.

This amendment includes:

Amendments to the Specification; and  
Remarks.